

RJH1CV6DPK

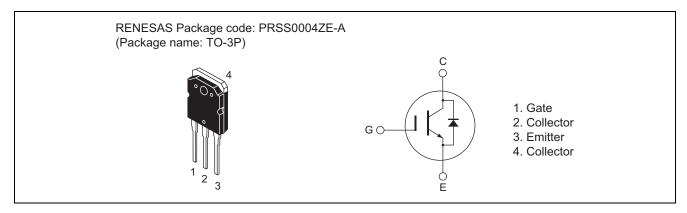
1200V - 30A - IGBT Application: Inverter

R07DS0747EJ0300 Rev.3.00 Feb 14, 2013

Features

- Short circuit withstand time (5 µs typ.)
- Low collector to emitter saturation voltage $V_{CE(sat)} = 1.8 \text{ V}$ typ. (at $I_C = 30 \text{ A}, V_{GE} = 15 \text{ V}, Ta = 25^{\circ}\text{C}$)
- Built-in fast recovery diode ($t_{rr} = 180 \text{ ns typ.}$) in one package
- Trench gate and thin wafer technology
- High speed switching t_f = 120 ns typ. (at V_{CC} = 600 V, V_{GE} = 15 V, I_C = 30 A, Rg = 5 Ω , Ta = 25°C, inductive load)

Outline



Absolute Maximum Ratings

 $(Ta = 25^{\circ}C)$

Item		Symbol	Ratings	Unit
Collector to emitter voltage / diode reverse voltage		V _{CES} / V _R	1200	V
Gate to emitter voltage		V_{GES}	±30	V
Collector current	Tc = 25°C	Ic	60	А
	Tc = 100°C	Ic	30	А
Collector peak current		ic(peak) Note1	90	А
Collector to emitter diode forward current		I _{DF}	30	А
Collector to emitter diode forward peak current		i _{DF} (peak) Note1	90	А
Collector dissipation		P _C Note2	290	W
Junction to case thermal resistance (IGBT)		θj-c Note2	0.43	°C/W
Junction to case thermal resistance (Diode)		θj-cd ^{Note2}	0.69	°C/W
Junction temperature		Tj	150	°C
Storage temperature		Tstg	-55 to +150	°C

Notes: 1. PW \leq 10 μ s, duty cycle \leq 1%

2. Value at Tc = 25°C

Electrical Characteristics

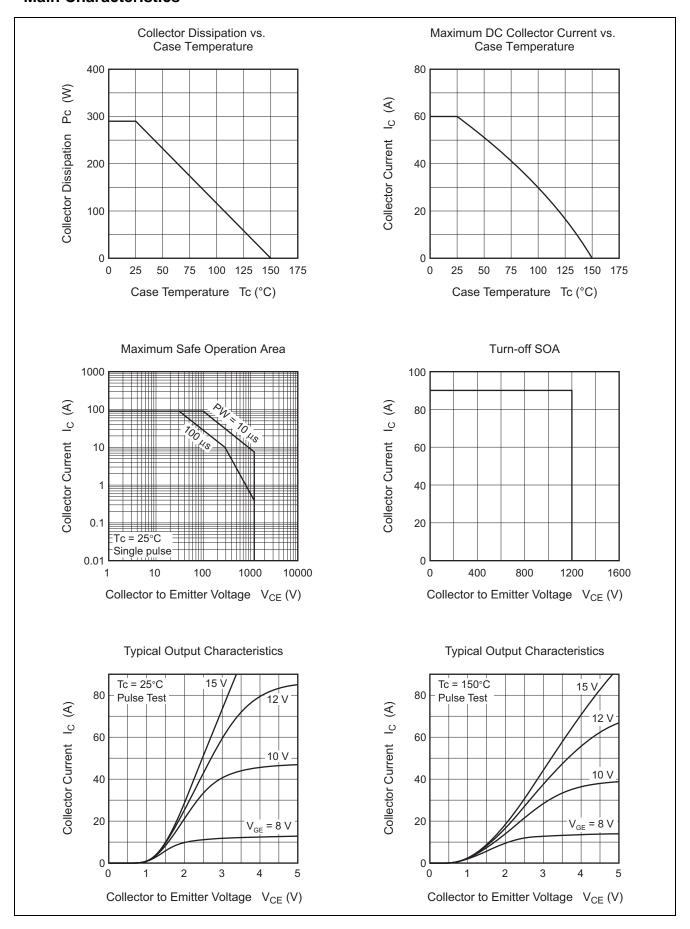
 $(Ta = 25^{\circ}C)$

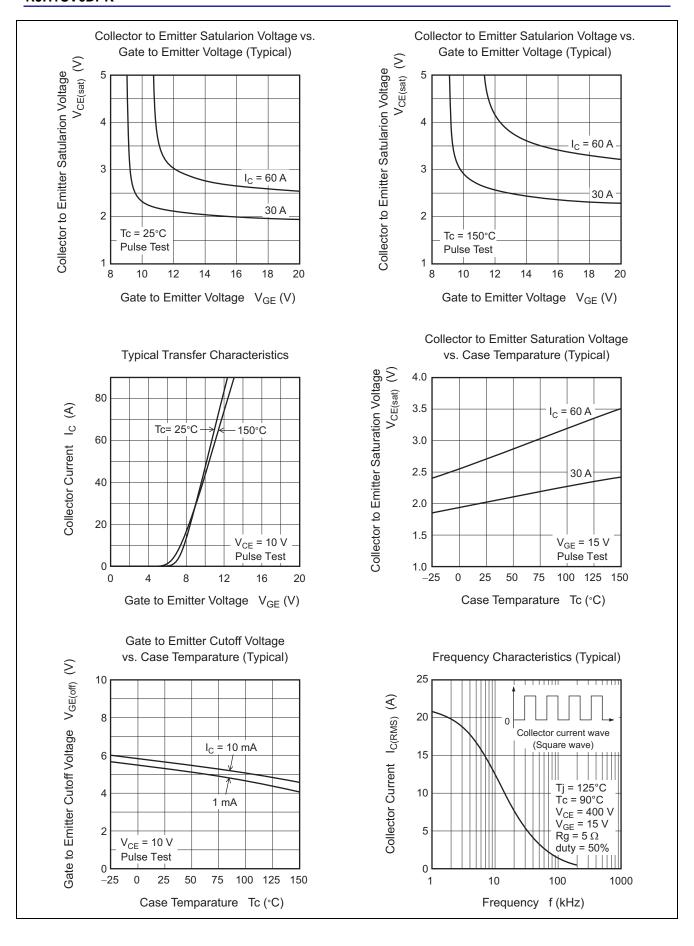
Item	Symbol	Min	Тур	Max	Unit	Test Conditions	
Zero gate voltage collector current / Diode reverse current	I _{CES} /I _R	_	_	5	μА	V _{CE} = 1200 V, V _{GE} = 0	
Gate to emitter leak current	I _{GES}	_	_	±1	μΑ	$V_{GE} = \pm 30 \text{ V}, V_{CE} = 0$	
Gate to emitter cutoff voltage	V _{GE(off)}	4.5	_	6.5	V	V _{CE} = 10 V, I _C = 1 mA	
Collector to emitter saturation voltage	V _{CE(sat)}	_	1.8	2.6	V	$I_C = 30 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
	V _{CE(sat)}	_	2.6	_	V	$I_C = 60 \text{ A}, V_{GE} = 15 \text{ V}^{\text{Note3}}$	
Input capacitance	Cies	_	1600	_	pF	V _{CE} = 25 V	
Output capacitance	Coes	_	85	_	pF	V _{GE} = 0 f = 1 MHz	
Reverse transfer capacitance	Cres	_	43	_	pF		
Total gate charge	Qg	_	105	_	nC	V _{GE} = 15 V V _{CE} = 300 V I _C = 35 A	
Gate to emitter charge	Qge	_	14	_	nC		
Gate to collector charge	Qgc	_	55	_	nC		
Turn-on delay time	t _{d(on)}	_	46	_	ns	V _{CC} = 600 V	
ise time	t _r	_	33	_	ns	V _{GE} = 15 V	
Turn-off delay time	t _{d(off)}	_	125	_	ns	$I_C = 30 \text{ A}$ $Rg = 5 \Omega$	
Fall time	t _f	_	120	_	ns		
Turn-on energy	Eon	_	2.3	_	mJ	Inductive load	
Turn-off energy	E _{off}	_	1.7	_	mJ		
Total switching energy	E _{total}	_	4.0	_	mJ		
Short circuit withstand time	t _{sc}	_	5	_	μS	$V_{CC} \le 720 \text{ V}, V_{GE} = 15 \text{ V}$	
						Tc ≤ 125°C	
FRD forward voltage	V_{F}	_	2.0	_	V	I _F = 30 A ^{Note3}	
FRD reverse recovery time	t _{rr}	_	180	_	ns	$I_F = 30 \text{ A}$	

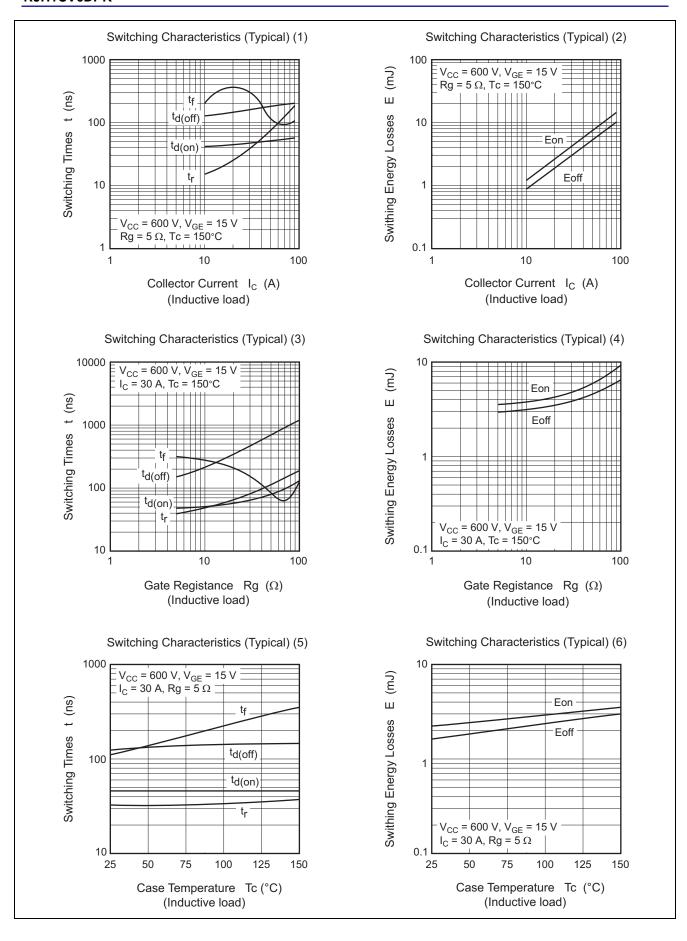
FRD forward voltage	V_{F}	_	2.0		V	$I_F = 30 \text{ A}^{\text{Note3}}$
FRD reverse recovery time	t _{rr}	_	180	_	ns	I _F = 30 A
FRD reverse recovery charge	Q _{rr}	_	0.63		μС	$di_F/dt = 100 A/\mu s$
FRD peak reverse recovery current	I _{rr}	_	9.2	_	Α	

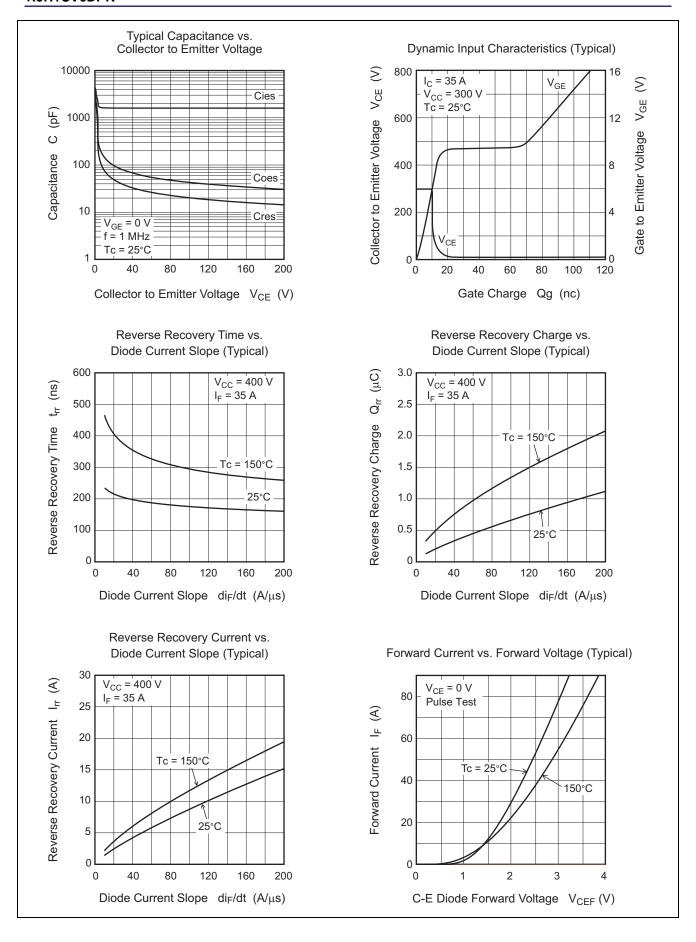
Notes: 3. Pulse test.

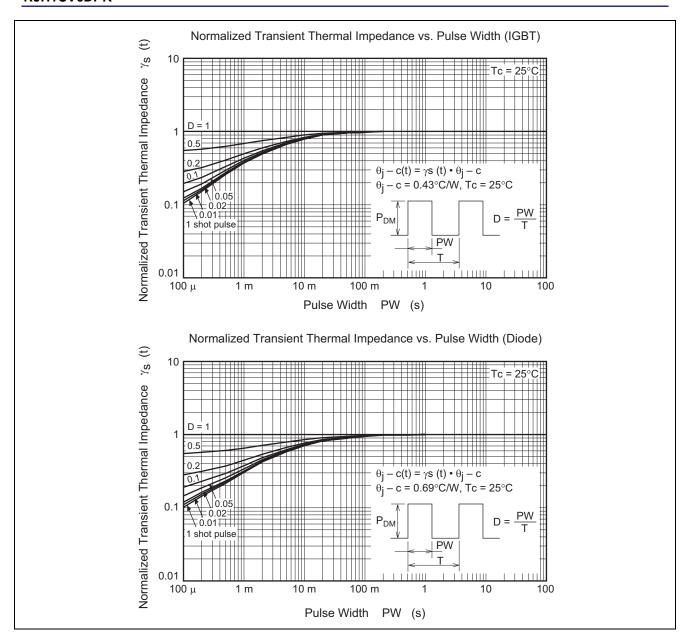
Main Characteristics

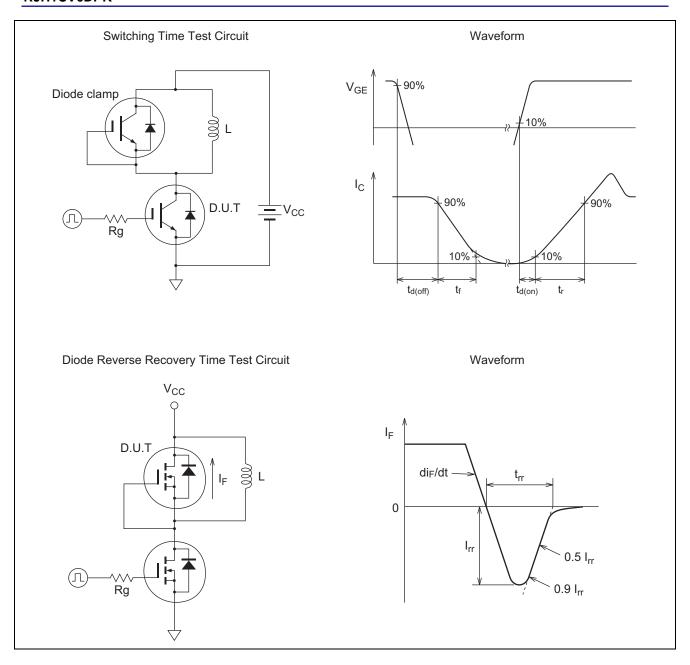




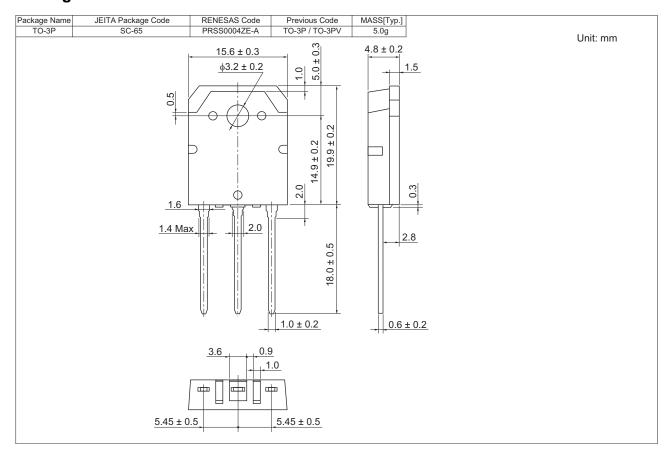








Package Dimension



Ordering Information

Orderable Part Number	Quantity	Shipping Container
RJH1CV6DPK-00#T0	30 pcs	Tube

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Renesas Electronics America Inc. 2880 Scott Boulevard Santa Clara, CA 95050-2554, U.S.A. Tel: +1-408-588-6000, Fax: +1-408-588-6130

Renesas Electronics Canada Limited 1101 Nicholson Road, Newmarket, Ontario L3Y 9C3, Canada Tel: +1-905-898-5441, Fax: +1-905-898-3220

Renesas Electronics Europe Limited
Dukes Meadow, Milliboard Road, Bourne End, Buckinghamshire, SL8 5FH, U.K
Tel: +44-1628-651-700, Fax: +44-1628-651-804

Renesas Electronics Europe GmbH

Arcadiastrasse 10, 40472 Düsseldorf, Germany Tel: +49-211-65030, Fax: +49-211-6503-1327

Renesas Electronics (China) Co., Ltd. 7th Floor, Quantum Plaza, No.27 ZhiChunLu Ha Tel: +86-10-8235-1155, Fax: +86-10-8235-7679 i. nunLu Haidian District. Beiiing 100083. P.R.China

Renesas Electronics (Shanghai) Co., Ltd.
Unit 204, 205, AZIA Center, No.1233 Lujiazui Ring Rd., Pudong District, Shanghai 200120, China Tel: +86-21-5877-1818, Fax: +86-21-6887-7858 / -7898

Renesas Electronics Hong Kong Limited
Unit 1601-1613, 16/F., Tower 2, Grand Century Place, 193 Prince Edward Road West, Mongkok, Kowloon, Hong Kong
Tel: +852-2868-9318, Fax: +852 2869-9022/9044

Renesas Electronics Taiwan Co., Ltd. 13F, No. 363, Fu Shing North Road, Taipei, Taiwan Tel: +886-2-8175-9600, Fax: +886 2-8175-9670

Renesas Electronics Singapore Pte. Ltd. 80 Bendemeer Road, Unit #06-02 Hyflux Innovation Centre Singapore 339949 Tel: +65-6213-0200, Fax: +65-6213-0300

Renesas Electronics Malaysia Sdn.Bhd. Unit 906, Block B, Menara Amcorp, Amcorp Trade Centre, No. 18, Jln Persiaran Barat, 46050 Petaling Jaya, Selangor Darul Ehsan, Malaysia Tel: +60-3-7955-9390, Fax: +60-3-7955-9510

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